NSN 5961-01-358-2682

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-358-2682 **Inclosure Material:** Ceramic or plastic **Overall Length:** Between 0.790 inches and 0.800 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.249 inches and 0.260 inches **Overall Width:** Between 0.535 inches and 0.545 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage **Current Rating Per Characteristic:** 34.00 amperes zero-gate-voltage source current any acceptable and 34.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/592 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**